In the Specification:

Page 4, paragraph 2, lines 9-30 should read as follows:



More particularly, the level-shifting section 12 includes an input transistor N₁ having a control, here gate, electrode coupled to a +2.1 volt supply, a first electrode coupled to the input logic signal IN, and a second electrode. An output pair of serially coupled complementary type transistors, i.e., P type MOSFET P₂ and N type MOSFET N₂, is provided. A first one of the pair of transistors P₂ has a first electrode coupled to a source, not shown, of the third voltage level (+2.5 volts) through a first switching transistor P type MOSFET P₃ and a control electrode coupled to the second electrode of the input transistor N₁. A junction 16 between the output pair of transistors P₂, N₂ provides the output terminal OUT for the level-shifting circuitry 10. A control electrode of the second one of the pair of transistors N₂ is connected to the first electrode of the input transistor N₁. The second one of the pair of transistors N₂ has a second electrode coupled to the second voltage level, here ground, through a second switching transistor N₃. The first and second switching transistors P-type MOSFET P₃ and N-Type MOSFET N₃ are fed by the enable/disable signal ENABLE, the transistor P₃ being coupled to the enable/disable signal ENABLE via an inverter 18, as shown. The level-shifting section 12 includes an additional transistor P type MOSFET P₁. The additional transistor P₁ has a control electrode connected to the junction 16, a first electrode coupled to the source of the third voltage level +2.5 through the first switching transistor P₃ and a second electrode connected to the second electrode of the input transistor N_1 . The input transistor N_1 and the additional transistor P_1 are of opposite conductivity type. The enable/disable circuit 14 includes an inverter 18 fed by the enable/disable signal ENABLE. The inverter 18 having an output coupled to the control electrode of the first switching transistor P₃.